

Data sheet acquired from Harris Semiconductor SCHS068A – Revised March 2002

# CD4503B Types

## **CMOS Hex Buffer**

# High-Voltage Types (20-Volt Rating) 3-State Non-Inverting Type

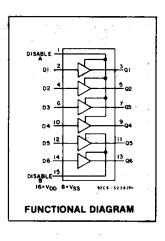
■CD4503B is a hex noninverting buffer with 3-state outputs having high sink- and source-current capability. Two disable controls are provided, one of which controls four buffers and the other controls the remaining two buffers. The CD4503B types are supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline package (NSR suffix), and in chip form (H suffix).

### Features:

- 1 TTL-load output drive capability
- 2 output disable controls
- 3-state outputs
- Pin compatible with industry types MM80C97, MC14503, and 340097
- 5-V, 10-V, and 15-V parametric ratings
- Maximum input current of 1 µA at 18 V over full package temperature range; 100 nA at 18 V and 25°C
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

#### Applications:

- 3-state hex buffer for interfacing IC's with data buses
- CMOS to TTL hex buffer



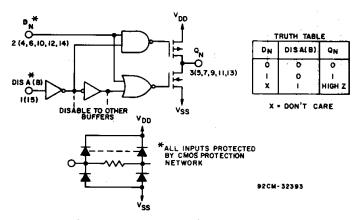


Fig. 1—Logic diagram of 1 to 6 identical buffers.

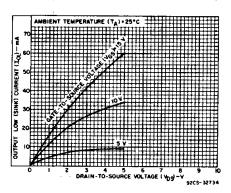


Fig. 2—Typical n-channel output low (sink) current characteristics.

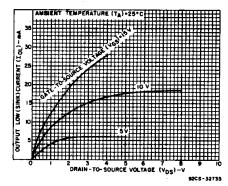
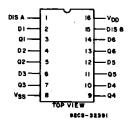


Fig. 3—Minimum n-channel output low (sink) current characteristics.



**TERMINAL ASSIGNMENT** 

## MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (VDD)	•
Voltages referenced to VSS Terminal)	0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS	0.5V to Vnn +0.5V
DC INPUT CURRENT, ANY ONE INPUT	±10mA
POWER DISSIPATION PER PACKAGE (PD):	
For TA = -55°C to +100°C	500mW
For T <sub>A</sub> = +100°C to +125°C	t 12mW/°C to 200mW
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)	100mW
OPERATING-TEMPERATURE RANGE (TA)	55°C to +125°C
STORAGE TEMPERATURE RANGE (Tstg)	65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s may	+26500

## CD4503B Types

## STATIC ELECTRICAL CHARACTERISTICS

CHARAC- TERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)						726	
	Vo	Vin	VDD				<del></del>	T			
	(x)	(V)	(8)	<b>—55</b>	-40	+ 85	+ 125	Min.	+ 25 Typ.	Max.	S
Quiescent	_	0,5	5	1	1	30	30	_	0.02	1	
Device		0,10	10	2	2	60	60	_	0.02	2	
Current,	_	0,15	15	4	4	120	120		0.02	4	μΑ
IDD Max.	_	0,20	20	20	20	600	600		0.04	20	
Output				Ĭ			-				
Low	0.4	0	5	2.6	2.5	1.4	1.3	2.1	2.3	. —	
(Sink)	0.5	0	10	6.5	6.4	3.9	3.8	5.5	6.2		·
Current	1.5	0	15	19.2	18.9	11.4	11.2	16.1	23	_	
IOL Min.				[	1	l			ļ		
Output	4.6	5	5	10	1.40	0.7			4.0		
High	2.5	5	5	-1.2 5.8	-1.16		-0.7	-1.02			m/
(Source)	9.5	10		<del>3.0</del>	-5.7 -3	-3.4	-3	<b>−4.8</b>	<u>-6.1</u>		
Current,		15	10 15	8.2	—3 —8	<u>-1.9</u>	-1.8 -4.8	-2.6	-3.7		
IOH Min.	13.5	15	15	0.2	-0	-4.9	-4.8	<b>—6.8</b>	<b>—14.1</b>		
Output	· · · · · ·				:						
Voltage:	_ ^	0,5	5		0.0	05			١٥	0.05	
Low-				0.00							
Level,		0,10	10		0.05			_	ا ا	0.05	
VOL Max.	٠٠ ـــــــــــــــــــــــــــــــــــ	0,15	15	0.05				0	0.05		
Output							-		-	0.00	٧
Voltage:		0,5	5		4.9	95		4.95	5	_	
High-				4.95							
Level,	_	0,10	10		9.95			9.95	10		
VOH Min.	_	0,15	15					14.95	15		
Input Low	0.5,4.5		5			5		-	- 13	1.5	
Voltage,	1,9	_	10		3		1 2	ΗΞ-		3	
VII Max.	1.5,13.5		15	<b></b>				= -		-4	
Input	1.0,10.0			<del> </del>		<u> </u>	,	=-		-	
High	0.5,4.5		5	3.5			3.5			٧	
Voltage,	1,9		10		7	-		7			
Vill Min.	1.5,13.5		15	11			11	-			
Input	1.5, 15.5		- 13		· '	<u> </u>	_	''	=	_	<u> </u>
Current		0,18	18	± 0.1	± 0.1	±1	۱.,		± 10 <sup>-5</sup>	المدا	
IN Max.		0,16	10	= 0.1	± U. I	=	±1	-	= '''	± 0.1	
3-State	<u> </u>	-		<del> </del>	ļ	<del> </del>	-			$\vdash$	
						1					μΑ
Output	امیما	0.40	40		٠ ا				امحما	اريا	
Leakage	0,18	0,18	18	±0.4	± 0.4	± 12	± 12	-	± 10 <sup>-4</sup>	± 0.4	
Current,							[				
OUT							1				7
Max.									j		



For maximum reliability, nominal operating conditions should be selected that operation is always within the following ranges:

	-	•	200
CHARACTERISTIC -	LIA	HAUTE	
	Min.	Max.	UNITS
Supply-Voltage Range (For TA = Full Package-Temperature Range)	3	18	٧

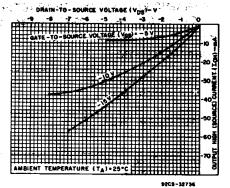


Fig. 4—Typical p-channel output high (source) current characteristics.

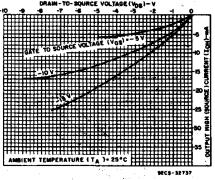


Fig. 5—Minimum p-channel output high (source) current characteristics.

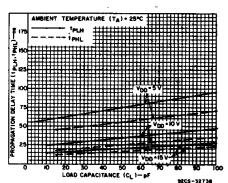


Fig. 6—Typical propagation delay time as a function of load capacitance.

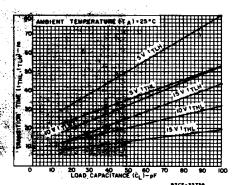


Fig. 7—Typical transition time as a function of load capacitance.

## CD4503B Types

## DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A=25^{\circ}C$ ; input $t_f$ , $t_f=20$ ns, $C_L=50$ pF, $R_L=200$ k $\Omega$ unless otherwise specified.

CHARACTERISTIC	V <sub>DD</sub>	LIN		
CHARACTERISTIC	(v)	Typ.	Max.	UNITS
Propagation Delay Time:	5	75	150	
Low-to-High, tpLH	10	35	70	ns
	15	25	50	
High-to-Low, tpHL	5	55	110	
	10	25	50	ns
	15	17	35	
Transition Time:	5	50	90	
Low-to-High, t <sub>TLH</sub>	10	30	45	ns
	15	25	35	
High-to-Low, t <sub>THL</sub>	5	35	70	
	10	20	40	ns
	15	13	25	
3-State Propagation Delay Time: R <sub>L</sub> = 1 kΩ	5	70	140	
tPHZ, tPZH	10	30	60	ns
	15	25	50	
tPZL, tPLZ	5	90	180	
	10	40	80	ns
	15	35	70	ŀ

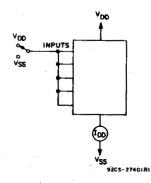
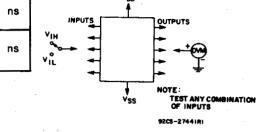


Fig. 10-Quiescent-device-current test circuit.



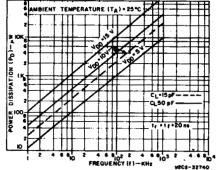


Fig. 8—Typical power dissipation as a function of frequency.

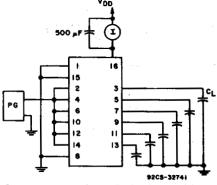
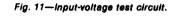


Fig. 9—Dynamic power dissipation test circuit.



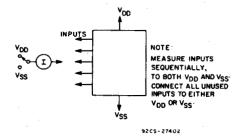
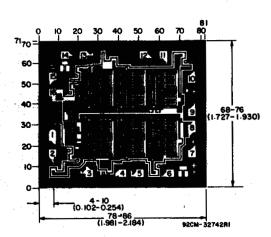


Fig. 12-Input current test circuit.



## Dimensions and pad layout for CD4503BH

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10<sup>-3</sup> inch):

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